

DTN20N65SJ/DTP20N65SJ/DTP20N65FSJ/DTK20N65SJ

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N-Channel 650-V (D-S) Super Junction MOSFET

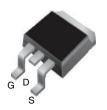
PRODUCT SUMMA	RY	
V _{DS} (V) at T _J max.	650)
R _{DS(on)} max. (Ω) at 25 °C	V _{GS} = 10 V	0.19
Q _g max. (nC)	106	6
Q _{gs} (nC)	14	
Q _{gd} (nC)	33	
Configuration	Sing	le

FEATURES

- Reduced t_{rr}, Q_{rr}, and I_{RRM}
- Low figure-of-merit (FOM) Ron x Qg
- Low input capacitance (Ciss)
- Low switching losses due to reduced Q_{rr}
- Ultra low gate charge (Qa)
- Avalanche energy rated (UIS)



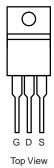
D2PAK (TO-263)



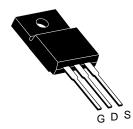
APPLICATIONS

- Telecommunications
 - Server and telecom power supplies
- Lighting
 - High-intensity discharge (HID)
 - Fluorescent ballast lighting
- · Consumer and computing
 - ATX power supplies
- Industrial
 - Welding
 - Battery chargers
- Renewable energy
 - Solar (PV inverters)
- Switch mode power supplies (SMPS)





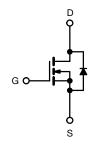
TO-220 FULLPAK



Top View



Top View



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C	= 25 °C, unl	ess otherwis	se noted)		
PARAMETER			SYMBOL	LIMIT	UNIT
Drain-Source Voltage			V_{DS}	650	V
Gate-Source Voltage			V_{GS}	± 30	7 °
Continuous Proin Current (T = 150 °C)	\/ at 10 \/	$T_C = 25 ^{\circ}C$ $T_C = 100 ^{\circ}C$		20	
Continuous Drain Current (T _J = 150 °C)	V _{GS} at 10 V	T _C = 100 °C	I _D	13	Α
Pulsed Drain Current ^a			I _{DM}	53	1
Linear Derating Factor				1.7	W/°C
Single Pulse Avalanche Energy b			E _{AS}	367	mJ
Maximum Power Dissipation			P_{D}	208	W
Operating Junction and Storage Temperature Range	Э		T _J , T _{stg}	-55 to +150	°C
Drain-Source Voltage Slope T _J = 125 °C			-15.77-11	37	V/ns
Reverse Diode dV/dt ^d			dV/dt	31	v/ns
Soldering Recommendations (Peak Temperature) c for 10 s		10 s		300	°C

Notes

- a. Repetitive rating; pulse width limited by maximum junction temperature. b. $V_{DD}=50$ V, starting $T_J=25$ °C, L=28.2 mH, $R_g=25$ Ω , $I_{AS}=5.1$ A.
- c. 1.6 mm from case.
- d. $I_{SD} \le I_D$, dI/dt = 100 A/ μ s, starting $T_J = 25$ °C.



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THERMAL RESISTANCE RATI	NGS			
PARAMETER	SYMBOL	TYP.	MAX.	UNIT
Maximum Junction-to-Ambient	R _{thJA}	-	62	°C/W
Maximum Junction-to-Case (Drain)	R_{thJC}	-	0.5	G/ VV

PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static		-					
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} :	= 0 V, I _D = 250 μA	650	-	-	V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	Reference	e to 25 °C, I _D = 1 mA	=.	0.67	-	V/°C
Gate-Source Threshold Voltage (N)	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	2	-	4	V
Cata Carriaga Lagliaga			V _{GS} = ± 20 V	-	-	± 100	nA
Gate-Source Leakage	I _{GSS}		$V_{GS} = \pm 30 \text{ V}$	-	-	± 1	μΑ
Zava Cata Valtaga Dvain Cuwant		V _{DS} =	= 520 V, V _{GS} = 0 V	-	-	1	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 520 \	/, V _{GS} = 0 V, T _J = 125 °C	-	-	500	μA
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 11 A	-	0.19	-	Ω
Forward Transconductance	9 _{fs}	V _{DS}	= 30 V, I _D = 11 A	-	7.0	-	S
Dynamic		•				•	
Input Capacitance	C _{iss}		$V_{GS} = 0 V$	-	2322	-	
Output Capacitance	C _{oss}	7	$V_{DS} = 100 \text{ V},$	-	105	-	
Reverse Transfer Capacitance	C _{rss}	7	f = 1 MHz	-	4	-	
Effective Output Capacitance, Energy Related ^a	C _{o(er)}	V _{DS} = 0 V to 520 V, V _{GS} = 0 V		-	84	-	pF
Effective Output Capacitance, Time Related ^b	C _{o(tr)}			-	293	-	
Total Gate Charge	Q_g			-	71	106	
Gate-Source Charge	Q _{gs}	V _{GS} = 10 V	$I_D = 11 A, V_{DS} = 520 V$	-	14	-	nC
Gate-Drain Charge	Q _{gd}	1		-	33	-	
Turn-On Delay Time	t _{d(on)}			-	22	44	
Rise Time	t _r	V _{DD} =	= 520 V, I _D = 11 A,	-	34	68	
Turn-Off Delay Time	t _{d(off)}	V _{GS} =	= 10 V, $R_g = 9.1 \Omega$	-	68	102	ns
Fall Time	t _f			=.	42	84	
Gate Input Resistance	R _g	f = 1	MHz, open drain	=	0.78	-	Ω
Drain-Source Body Diode Characteristic	s						•
Continuous Source-Drain Diode Current	I _S	MOSFET symbol showing the		-	-	21	
Pulsed Diode Forward Current	I _{SM}	integral revers		-	-	53	A
Diode Forward Voltage	V _{SD}	T _J = 25 °C	C, I _S = 11 A, V _{GS} = 0 V	-	0.9	1.2	V
Reverse Recovery Time	t _{rr}	Ť		-	160	-	ns
Reverse Recovery Charge	Q _{rr}		5 °C, I _F = I _S = 11 A,	-	1.2	-	μC
Reverse Recovery Current	I _{RRM}	ai/at =	100 A/ μ s, V _R = 25 V	_	14	 -	A

- a. $C_{oss(er)}$ is a fixed capacitance that gives the same energy as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DSS} . b. $C_{oss(tr)}$ is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DSS} .

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

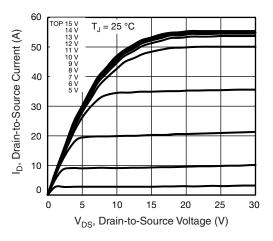


Fig. 1 - Typical Output Characteristics

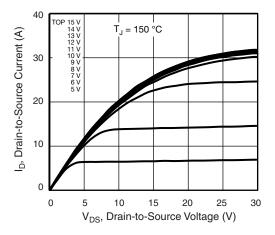


Fig. 2 - Typical Output Characteristics

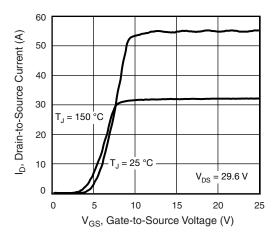


Fig. 3 - Typical Transfer Characteristics

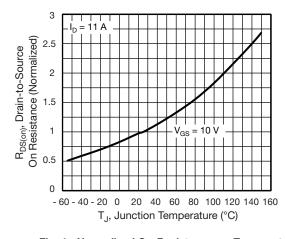


Fig. 4 - Normalized On-Resistance vs. Temperature

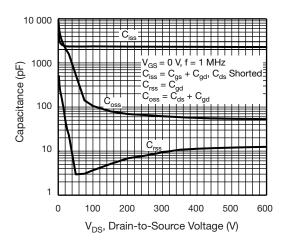


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage

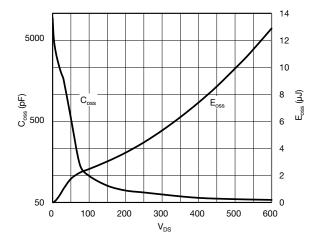


Fig. 6 - Coss and Eoss vs. VDS

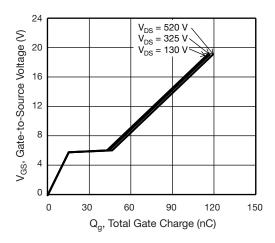


Fig. 7 - Typical Gate Charge vs. Gate-to-Source Voltage

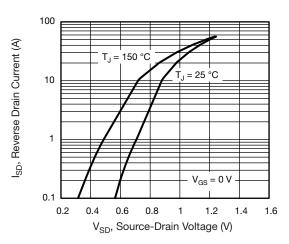


Fig. 8 - Typical Source-Drain Diode Forward Voltage

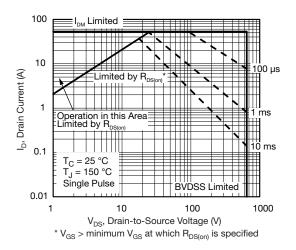


Fig. 9 - Maximum Safe Operating Area

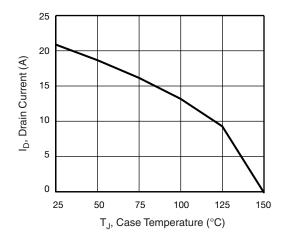


Fig. 10 - Maximum Drain Current vs. Case Temperature

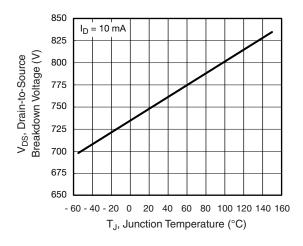


Fig. 11 - Temperature vs. Drain-to-Source Voltage

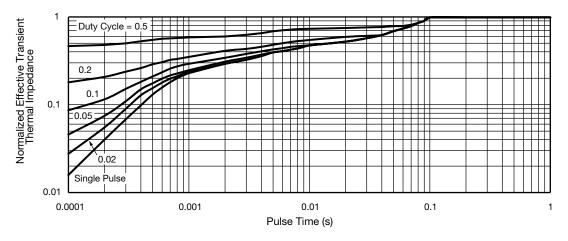


Fig. 12 - Normalized Thermal Transient Impedance, Junction-to-Case

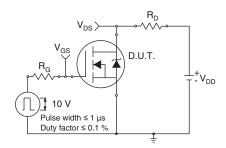


Fig. 13 - Switching Time Test Circuit

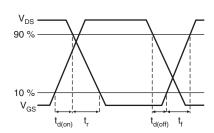


Fig. 14 - Switching Time Waveforms

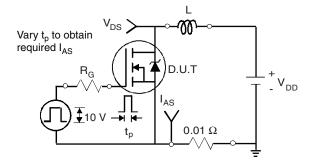


Fig. 15 - Unclamped Inductive Test Circuit

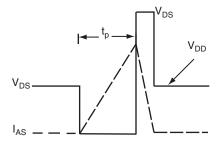


Fig. 16 - Unclamped Inductive Waveforms

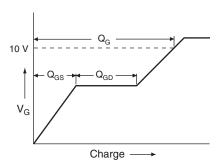


Fig. 17 - Basic Gate Charge Waveform

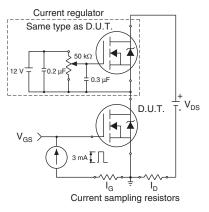
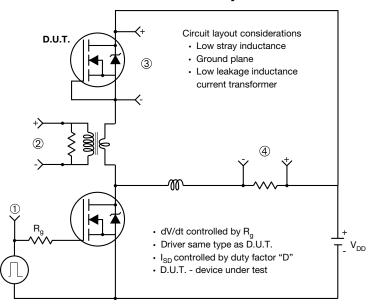


Fig. 18 - Gate Charge Test Circuit

Peak Diode Recovery dV/dt Test Circuit



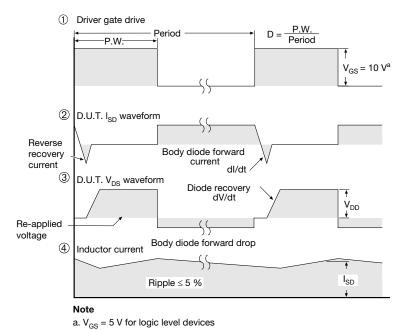
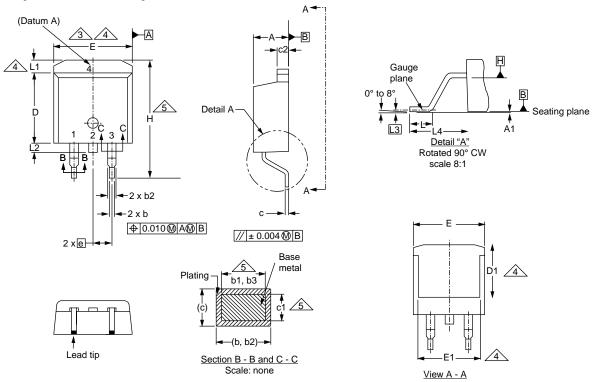


Fig. 19 - For N-Channel



TO-263AB (HIGH VOLTAGE)



	MILLIN	IETERS	INC	HES
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.06	4.83	0.160	0.190
A1	0.00	0.25	0.000	0.010
b	0.51	0.99	0.020	0.039
b1	0.51	0.89	0.020	0.035
b2	1.14	1.78	0.045	0.070
b3	1.14	1.73	0.045	0.068
С	0.38	0.74	0.015	0.029
c1	0.38	0.58	0.015	0.023
c2	1.14	1.65	0.045	0.065
D	8.38	9.65	0.330	0.380

	MILLIMETERS		INC	HES	
DIM.	MIN.	MAX.	MIN.	MAX.	
D1	6.86	-	0.270	-	
Е	9.65	10.67	0.380	0.420	
E1	6.22	-	0.245	-	
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	
L2	-	1.78	-	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

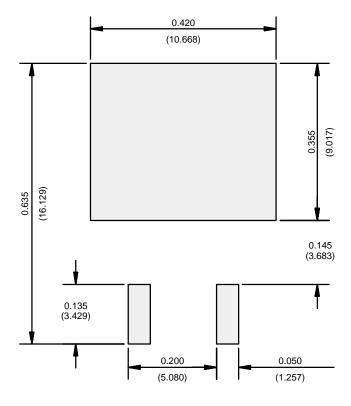
ECN: S-82110-Rev. A, 15-Sep-08 DWG: 5970

Notes

- 1. Dimensioning and tolerancing per ASME Y14.5M-1994.
- 2. Dimensions are shown in millimeters (inches).
- 3. Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body at datum A.
- 4. Thermal PAD contour optional within dimension E, L1, D1 and E1.
- 5. Dimension b1 and c1 apply to base metal only.
- 6. Datum A and B to be determined at datum plane H.
- 7. Outline conforms to JEDEC outline to TO-263AB.



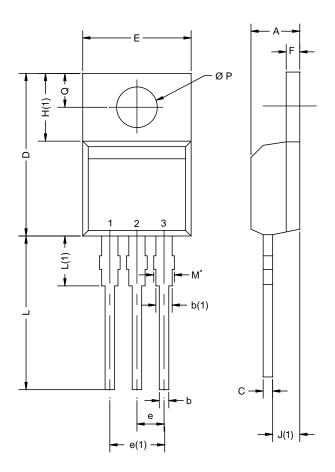
RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)



TO-220AB



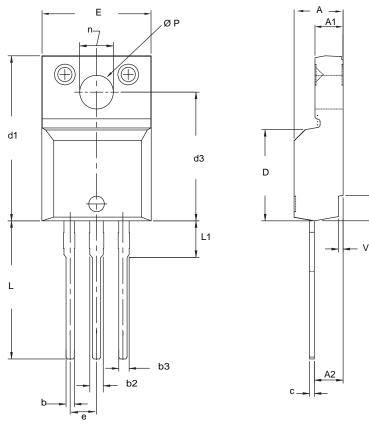
	MILLIN	IETERS	INC	HES
DIM.	MIN.	MAX.	MIN.	MAX.
Α	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
С	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
Е	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
ØР	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
ECN: X12-0 DWG: 5471)208-Rev. N,	08-Oct-12		

Notes

 $^{^{\}star}$ M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



TO-220 FULLPAK (HIGH VOLTAGE)



	MILLIN	METERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
Α	4.570	4.830	0.180	0.190	
A1	2.570	2.830	0.101	0.111	
A2	2.510	2.850	0.099	0.112	
b	0.622	0.890	0.024	0.035	
b2	1.229	1.400	0.048	0.055	
b3	1.229	1.400	0.048	0.055	
С	0.440	0.629	0.017	0.025	
D	8.650	9.800	0.341	0.386	
d1	15.88	16.120	0.622	0.635	
d3	12.300	12.920	0.484	0.509	
E	10.360	10.630	0.408	0.419	
е	2.54	BSC	0.100 BSC		
L	13.200	13.730	0.520	0.541	
L1	3.100	3.500	0.122	0.138	
n	6.050	6.150	0.238	0.242	
ØΡ	3.050	3.450	0.120	0.136	
u	2.400	2.500	0.094	0.098	
V	0.400	0.500	0.016	0.020	

DWG: 5972

- To be used only for process drawing.
 These dimensions apply to all TO-220, FULLPAK leadframe versions 3 leads.
 All critical dimensions should C meet C_{pk} > 1.33.
 All dimensions include burrs and plating thickness.
 No chipping or package damage.





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